

isc N-Channel MOSFET Transistor

IRLI3705N, IIRLI3705N

• FEATURES

- Low drain-source on-resistance:
 R_{DS}(on) ≤ 1mΩ (max)
- Enhancement mode
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

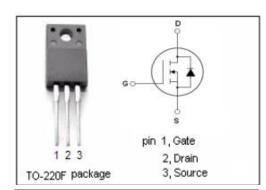
• reliable device for use in a wide variety of applications

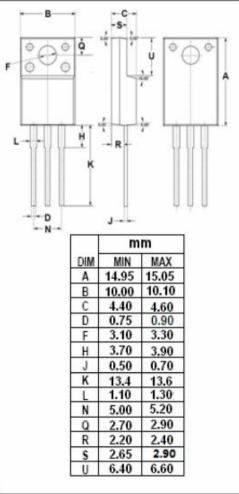
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
$V_{ extsf{DSS}}$	Drain-Source Voltage	55	V
V _{GS}	Gate-Source Voltage ±16		V
I _D	Drain Current-Continuous 52		А
I _{DM}	Drain Current-Single Pulsed	ent-Single Pulsed 310	
P _D	Total Dissipation @T _C =25℃	58	W
Tj	Max. Operating Junction Temperature	175	$^{\circ}\mathbb{C}$
T _{stg}	Storage Temperature	-55~175	${\mathbb C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	2.6	°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =0.25mA	55			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =250uA	1.0		2.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =28A			1	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±16V;V _{DS} = 0V			±100	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =55V; V _{GS} = 0V			25	μ А
V _{SD}	Diode forward voltage	I _{DR} =28A, V _{GS} = 0 V			1.3	V

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